

PC	N no.: PCN-092 r	ev.1.1		Date:	2014-10-31		
nR nR	evice affected: RF51822-QFAA RF51822-CEAA RF51822-QFAB			G00, G10,	rsion / Build Code: , G20, G30 , D20, D30		
	ita sheet references: e Appendix 1		Agreement reference: N/A		Customers reference: N/A		
Im	pact: Does the change	affect produc	t				
1.	Form	No No	Yes – describe:				
2.	Fit	No No	Yes – describe:				
3.	Function	No	🔀 Yes – describe: S	ee descrip	tion below		
4.	Quality or Reliability	No No	Yes – describe:				
Cla	ssification of change	Minor	Major	Major			
Im	pact: Does the change	affect <u>contair</u>	ier:				
5.	Form	🔀 No	Yes – describe:				
6.	Fit	No	🔀 Yes – describe: N	lew reel M	OQ for nRF51822-CEAA variant		
7.	Function	No No	Yes – describe:				
8.	Quality or Reliability	No No	Yes – describe:				
Cla	ssification of change	Minor	Major	Major			



Description of change:

New revision of the ICs, with the following key improvements/changes:

1. Radio and CPU concurrency

Support for running the CPU concurrently with the Radio. Key benefits include reduced application latency and increased CPU availability for application level code. New versions of the SoftDevices include APIs to enable/disable this feature. Refer to the SoftDevice documentation for more information.

2. Improved power efficiency

300 uA reduction in active current for CPU executing code from flash.

Improved buck DC/DC regulator. The new DC/DC only supplies the Radio. Optimizations include automatic management (application software only needs to enable/disable the feature) and improved power efficiency. Refer to the Product Specification and Reference Manual for more information.

3. Improved start-up time for Power on Reset (POR) module

Optimized POR module to provide faster start-up time across the whole supply range (1.8 to 3.6 V).

4. Fixes of anomalies

The new IC revision includes a number of fixes of anomalies reported in nRF51822-PAN v2.4. For an updated list of anomalies refer to the new nRF51822-PAN v3.0.

- 5. New container options for the CSP package variants
- nRF51822-CEAA-R (Reel) MOQ changed from 3000 to 7000
- New 7" reel option: nRF51822-CEAA-R7 with a MOQ of 1500

Refer to the Product Specification version 3.1 for more information.

All new features and changes in electrical specifications for the new revision are documented in the nRF51822 Product Specification version 3.1 and the nRF51 Reference Manual version 3.0. Appendix 1 lists all changes with reference to these documents.

Reason for change:

New features, bug fixes, and improvements of performance and power efficiency.



Consequences of change:

1. Hardware

None. New revisions are drop-in compatible with the current revisions.

2. Teleregulatory and Bluetooth certification

Reference designs nRF51822-DF (QFN) and nRF51822-CEAA-DF (CSP) pass all telecommunications regulatory bodies' requirements with the stated product changes with no discernible performance change. A reassessment of design performance due to applicable telecommunications regulatory requirements is required for any product not identical to the referenced designs.

Bluetooth QDIDs are valid for the new device versions *). Bluetooth RF PHY conformance reassessment is recommended for all designs not identical to the referenced designs.

3. Software

None. New revisions are software compatible with the current revisions including software workarounds for fixed anomalies.

To verify this, Nordic has carried out compatibility testing with the following software revisions:

- S110 v5.2.1, v6.2.1, and v7.1
- S120 v1.0.1
- nRF51 SDK v6.1 and v7.0

Note that the SDK v7.0 is compatible only with the new nRF51-DK and not the nRF51822-DK or nRF51822-EK.

*) For more information on migrating to the new revisions refer to the white paper nWP-021 *"Migrating from the 2nd to the 3rd revision of nRF51822"*, v.1.0.

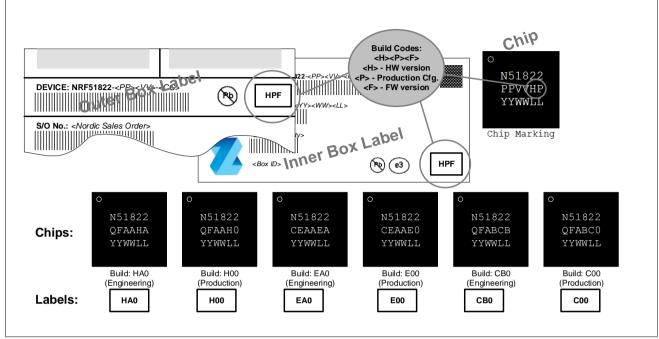
Verification of change:

New revisions are approved and qualified under standard Nordic Semiconductor ASA QA procedures.



Marking/Shipping labels:

The new versions will be marked with new build codes as follows:





nRF51822-QFAA (6x6mm QFN, 256kB Flash) Build Wafer / assembly Samples / reports Active from								
H00	TSMC Fab10 / AMKOR ATP	Now	2015-02-01					
		Second source buil	d codes:					
H10	TSMC Fab10 / ASE ChungLi	February 2015	Samples + 90 days					
H20	TSMC Fab3 / AMKOR ATP	To be announced	Samples + 90 days					
H30	TSMC Fab 3 / ASE ChungLi	To be announced	Samples + 90 days					

	nRF51822-CEAA (3.5x3.8mm CSP, 256kB Flash)								
Build	Active from								
code									
E00	TSMC Fab10 / Deca	Now	2015-02-01						
	Technologies								
		Second source buil	d codes:						
E10	TSMC Fab10 / ASE ChungLi	March 2015	Samples + 90 days						
E20	TSMC Fab3 / Deca	To be announced	Samples + 90 days						
	Technologies								
E30	TSMC Fab 3 / ASE ChungLi	To be announced	Samples + 90 days						

	nRF51822-QFAB (6x6mm QFN, 128kB Flash)							
Build code	Wafer / assembly	Samples / reports	Active from					
C00	C00 TSMC Fab10 / ASE ChungLi Now 2015-02-01							
		Second source buil	d codes:					
C10	TSMC Fab10 / Amkor ATP	February 2015	Samples + 90 days					
C20	TSMC Fab3 / ASE ChungLi	To be announced	Samples + 90 days					
C30	TSMC Fab3 / Amkor ATP	To be announced	Samples + 90 days					



Note that the above 'active from' dates refer to the earliest date Nordic will fulfill orders with the new revisions instead of the current revisions. Depending on stock level of current revision the actual 'active from' date may be later.

For the second source build codes, Nordic will update this PCN when the exact schedule of production samples and qualification report are available.

Nordic may on a limited basis support earlier ramp-up on the new revisions. Please contact Nordic sales for more information.

Last time order:			Final shi	pment date:		
N/A			N/A. Exis	ting stock to be depleted		
Attachments:	No	X Ye	es – descr	ibe: Appendix 1		
Technical contact at Nordic Sem	iconduc	tor:	Comme	rcial contact at Nordic Semiconductor:		
www.nordicsemi.com, "Support"			www.nordicsemi.com, "Contact Us"			
Authorization for Nordic Semico	onductor					
Product Manager	Date:	2014-10-28	Sign:	Thomas E. B.		
Quality Director	Date:	2014-10-28	Sign:	114P		

Please note that all last time buy orders are non-cancellable and non-returnable.

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Appendix 1

Product change summary

This is a summary of the changes implemented in the relevant product documentation:

Module	nRF51 Series Reference Manual v3.0 chapter	nRF51822 PS v3.1 chapter	Part changed/added	Comment			
RAM	5.1.4	3.2.2	RAM organization	The RAM is divided into multiple RAM AHB slaves. Added description on how to organize usages of the RAM to take advantages of multiple RAM AHB slaves.			
Power	12.1.1	3.4.1	Power Supply	Changed how the DC/DC and Regulators are organized. The DC/DC converter is only controlling the radio voltage.			
	12.1.3	3.4.1.2	DC/DC Converter setup	 Improved the DC/DC solution: Simplified how the DC/DC is controlled and operates. Removed the complexity around how it is controlled. Removed the startup time issue. 			
	12.1.7	3.4.2.2	System ON mode	Improved description around Low Power and Constant Latency			
	12.1.12		Power-on reset	The Power-on reset module has been improved on the startup time for the whole VDD range (1.8 to 3.6 V). No change in the descriptive text but it's seen on the numbers specified for the Power-on reset module below. Both in chapter 7 Operation condition and section 8.2 Power Management.			
Timer		4.2	Timer/ Counter	Added description about 1 MHz mode.			
Radio	17.1.3		Maximum packet length	Correction of documentation error. No change in actual performance between current revision and new revisions. The combined length of S0, LENGTH, S1, and PAYLOAD is changed from "cannot exceed 255 bytes" to "cannot exceed 254 bytes".			
	29.6		UART	New section "Suspending the UART"			
	33		Software Interrupts	New chapter			
Operating Condition		7	Table 20	Parameter t_{R_VDD} is specified under new conditions to reflect the improved POR module. Old parameter description: <i>Supply rise time (OV to 1.8 V)</i> New parameter description: <i>Supply rise time (O V to VDD)</i>			
				Symbol Old value New value Units t _{R VDD} 60 @ 0 - 1.8V 100 @ 0V - VDD ms			
System		8	Electrical specification	Changes in the electrical specification			
		8.1.2	Table 22	Symbol Old value New value Units I _{X16M.1M} New par. 250 μA			
		8.1.3	Table 23	Symbol Old value New value Units value I _{X32M,1M} New par. 300 μA			



Module	nRF51 Series Reference Manual v3.0 chapter	nRF51822 PS v3.1 chapter	Part changed/added	Comment				
		8.1.4	Table 24	Symbol		Old value	New value	Units
				I _{RC16M.1M}		New par.	540	μΑ
				t _{START,RC16M}	(Typ.)	2,5	4,2	μs
				t _{START,RC16M}	(Max.)	3,5	5,2	μs
						tion error. No cl rent revision an		
		8.1.6	Table 26	Symbol		Old value	New value	Units
				t _{START,RC32k}	(Typ.)	100	390	μs
				t _{START,RC32k}	(Max.)	New par.	487	μs
						tion error. No cl rent revision an		
		8.1.7	Table 27	Symbol		Old value	New value	Units
				t _{START,SYNT32}	k	100	406	μs
				Correction of	 documenta	tion error. No ci		
						rent revision an		
		8.2	Power management	The POR mode for the whole		oved so that it gi (1.8 to 3.6 V).	ves a fast sta	artup time
		8.2	Table 30	Symbol		Old value	New value	Units
				t _{POR, 1µs}	(Min, Typ)	Removed.		
				t _{POR, 50ms}	(Min, Typ)	Removed.		
				t _{POR, 10µs}	(Min.)	New par.	0,7	ms
				t _{POR, 10µs}	(Typ.)	New par.	2.4	ms
				t _{POR, 10µs}	(Max.)	New par.	19	ms
				t _{POR, 1ms}	(Min.)	New par.	1,7	ms
				t _{POR, 1ms}	(Typ.)	New par.	3.4	ms
				t _{POR, 1ms}	(Max.)	New par.	20	ms
				t _{POR, 10ms}	(Min.)	New par.	11	ms
				t _{POR, 10ms}	(Typ.)	New par.	12	ms
				t _{POR, 10ms}	(Max.)	New par.	28	ms
				t _{POR, 100ms}	(Min.)	New par.	68	ms
				t _{POR, 100ms}	(Typ.)	New par.	101	ms
				t _{POR} , 100ms	(Max.)	New par.	115	ms
			Table 32	Symbol		Old value	New value	Units
				I _{1V2XO16,1M}		New par.	520	μΑ
				I _{1V2XO32,1M}		New par.	560	μA
				I _{1V2RC16,1M}		New par.	630	μA
				t _{XO}	(Typ.)	New par.	2,3	μs
				t _{XO}	(Max.)	New par.	5,3	μs
				I _{DCDC}		Removed		
		8.3	Table 33	Updated. Add	ed row " CP	<i>Removed</i>	mn " 1V7" .	
		0.5						
		8.4	Table 34	Symbol		Old value	New	Units
				· ·		Old value 4,4	New value 4,1	Units



Module	nRF51 Series Reference Manual v3.0 chapter	nRF51822 PS v3.1 chapter	Part changed/added	Comment					
		8.5.3	Table 37 / Figure 11	 New section specifying Radio parameters when the DC/DC is enabled. New table 37 specifying the Radio current consumption when the DC/DC is enabled. Figure 11 gives the Conversion factor (F_{DCDC}) as function of VDD for selected radio modes. 					
		8.5.6	Table 40	Symbol t _{RXCHAIN} (250 k) t _{RXCHAIN} (1 M) t _{RXCHAIN} (2 M) Correction of documentar performance between current	Old value 12 2,5 tion error. No cl rent revision an	New value 12,5 3 2 hange in actu d new revisio	Units µs µs µs al ms.		
		8.7	Table 43	Symbol t _{CTSH}	Old value New par.	New value 1	Units µs		
		8.8	Table 45	Symbol t _{CD} Correction of documentation performance between cur					
		8.13	Table 52	Symbol I _{TIMER0/1/2,1M}	Old value New par.	New value 4	Units µA		
		8.15	Table 54	Improved the accuracy of the temperature sensor. Added a Note on T_{ACC} specifying that the accuracy is applicate the range from 0°C to +60°C.					
		8.22		Corrected the timing spec	cification for the	e NVMC mod	ule.		
			Table 61	Symbol	Old value	New value	Units		
				t _{ERASEALL} (Typ.) t _{ERASEALL} (Max.) t _{PAGEERASE} (Typ.) t _{PAGEERASEALL} (Max.) t _{WRITE} (Typ.) t _{WRITE,FLASH} (Max.) t _{WRITE,RAM,1st} (Max.) t _{WRITE,RAM,2nd} (Max.)	Removed New par. Removed New par. New par. New par. New par.	22.3 22.3 46,3 39,3 22,3	ms ms us us us		
				t _{WRITE,RAM,3rd} (Max.)	New par.	46,3	μs		
		8.24	Table 63	Symbol	Old value	New value	Units		
				t _{LPCOMPSTARTUP}	New par.	40	μs		